TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

2 S C 3 0 9 8

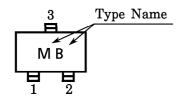
UHF~C BAND LOW NOISE AMPLIFIER APPLICATIONS

- Low Noise Figure
- $\bullet \qquad \mathrm{NF}\!=\!2.5\mathrm{dB},\; |S_{21e}|^2\!=\!14.5\mathrm{dB}\; (f\!=\!500\mathrm{MHz})$
- NF=3.0dB, $|S_{21e}|^2$ =9.0dB (f=1GHz)

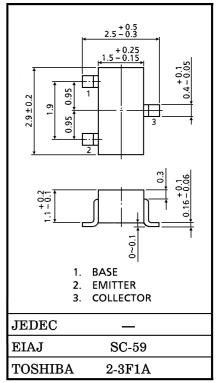
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	30	V
Collector-Emitter Voltage	v_{CEO}	20	V
Emitter-Base Voltage	$V_{ m EBO}$	3	V
Collector Current	$^{\mathrm{I}}\mathrm{C}$	50	mA
Base Current	$I_{\mathbf{B}}$	25	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	150	mW
Junction Temperature	$T_{ m j}$	125	°C
Storage Temperature Range	$T_{ m stg}$	-55~125	°C

Marking



Unit in mm



Weight: 0.012g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Transition Frequency	$ m f_{T}$	$V_{CE}=10V, I_{C}=10mA$		3.5	_	GHz
Ilngortion (Loin	$ S_{21e} ^2$ (1)	$V_{CE} = 10V, I_{C} = 10mA, f = 500MHz$		14.5	_	dB
	$ S_{21e} ^2$ (2)	$V_{CE}=10V$, $I_{C}=10mA$, $f=1GHz$		9	_	dB
Noise Figure	NF (1)	$V_{CE}=10V$, $I_{C}=5mA$, $f=500MHz$	_	2.5	_	dB
	NF (2)	V_{CE} =10V, I_{C} =5mA, f =1GHz		3	_	dB

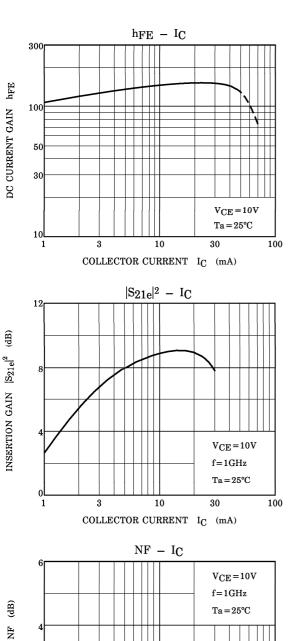
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

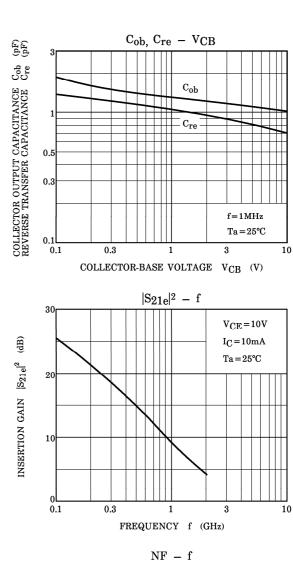
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 10V, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_{C}=0$	_	_	1	μ A
DC Current Gain	$_{ m h_{FE}}$	$V_{\text{CE}} = 10 \text{V}, I_{\text{C}} = 10 \text{mA}$	30	80	300	_
Collecter Output Capacitance	$C_{ m ob}$	$V_{CB} = 10V, I_{E} = 0,$	_	1.15		pF
Reverse Transfer Capacitance	c_{re}	f=1MHz (Note)		0.75	_	pF

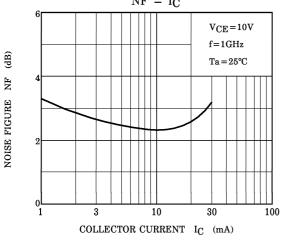
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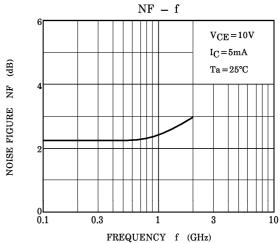
(Note) Cre is measured by 3-terminal method with Capacitance Bridge.

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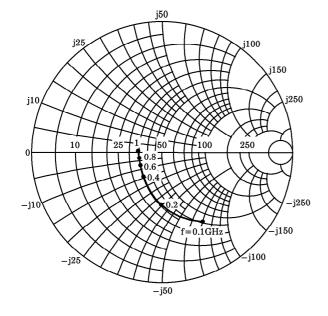


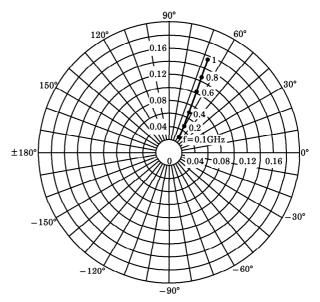


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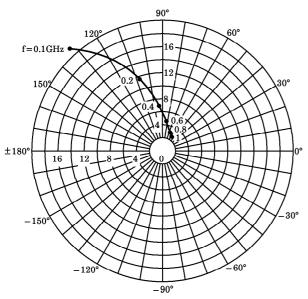
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 10mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$

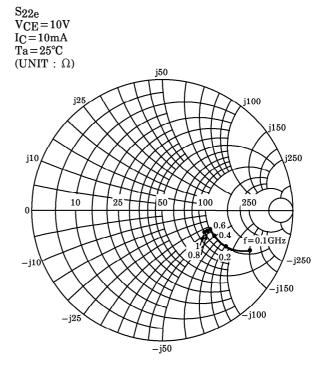






 $\begin{array}{c} S_{21e} \\ V_{CE} \! = \! 10V \\ I_{C} \! = \! 10mA \\ Ta \! = \! 25^{\circ}C \end{array}$





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